

8-Bit Bidirectional Voltage-Level Translator with Auto Direction sensing and ±15kV ESD Protection UM3308 CSP20 2.7×2.4

General Description

UM3308 is 8-channel bidirectional voltage level translator with auto direction sensing and $\pm 15 \mathrm{kV}$ ESD protection. This 8-channel noninverting translator uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.2V to 3.6V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65V to 5.5V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5V voltage nodes. Both I/O ports are auto-sensing; thus, no direction pin is required, making it ideal for data transfer between low-voltage ASICs/PLDs and higher voltage systems.

The UM3308 operates at a guaranteed data rate of 20Mbps over the entire specified operating voltage range. Within specific voltage domains, higher data rates are up to 100Mbps.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state. The UM3308 is designed so that the OE input circuit is supplied by $V_{\rm CCA}$.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The UM3308 is 8-channel level translator available in CSP20 2.7×2.4 bump package.

Applications

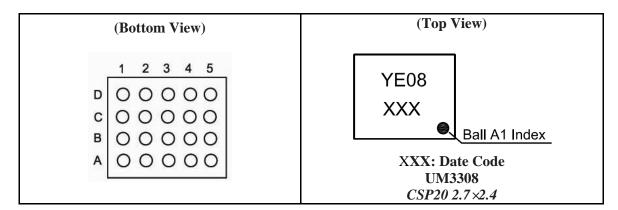
- Low-Voltage ASIC Level Translation
- Cell-Phone Cradles
- Portable POS Systems
- Portable Communication Devices
- Low-Cost Serial Interfaces
- Cell-Phones
- GPS
- Telecommunications Equipment

Features

- 1.2V to 3.6V on A Port and 1.65V to 5.5V on B Port ($V_{CCA} \le V_{CCB}$)
- V_{CC} Isolation Feature If Either V_{CC} Input is at GND, All Outputs are in the High-Impedance State
- OE Input Circuit Referenced to V_{CCA}
- Low Power Consumption
- Latch-Up Performance Exceeds 100mA
- ±15kV ESD Protection on B Ports

Pin Configurations

Top View





Terminal Assignments

	1	2	3	4	5
D	V_{CCB}	B2	B4	В6	B8
C	B1	В3	B5	В7	GND
В	A1	A3	A5	A7	OE
A	V_{CCA}	A2	A4	A6	A8

Pin Description

Pin Name	Function
A1	Input/Output 1. Referenced to V _{CCA}
V_{CCA}	A-Port supply voltage. $1.1V \le V_{CCA} \le 3.6V$ and $V_{CCA} \le V_{CCB}$
A2	Input/Output 2. Referenced to V _{CCA}
A3	Input/Output 3. Referenced to V _{CCA}
A4	Input/Output 4. Referenced to V _{CCA}
A5	Input/Output 5. Referenced to V _{CCA}
A6	Input/Output 6. Referenced to V _{CCA}
A7	Input/Output 7. Referenced to V _{CCA}
A8	Input/Output 8. Referenced to V _{CCA}
OE	3-state output enable. Pull OE low to place all outputs in 3-state mode.
OL	Referenced to V _{CCA}
GND	Ground
B8	Input/Output 8. Referenced to V _{CCB}
B7	Input/Output 7. Referenced to V _{CCB}
B6	Input/Output 6. Referenced to V _{CCB}
B5	Input/Output 5. Referenced to V _{CCB}
B4	Input/Output 4. Referenced to V _{CCB}
В3	Input/Output 3. Referenced to V _{CCB}
B2	Input/Output 2. Referenced to V _{CCB}
V_{CCB}	B-Port supply voltage. 1.65V\leq V_CCB\leq 5.5V
B1	Input/Output 1. Referenced to V _{CCB}

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM3308	CSP20 2.7×2.4	YE08	2500pcs/7Inch Tape & Reel



Absolute Maximum Ratings (Note 1)

Over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter		Value	Unit
V_{CCA}	Supply Voltage Range		-0.5 to +4.5	V
V_{CCB}	Supply Voltage Range		-0.5 to +6.5	V
V _I	Input Voltage Range (Note 2)	A ports B ports	-0.5 to +4.5 -0.5 to +6.5	V
V	Voltage Range applied to any	A ports	-0.5 to +4.5	V
Vo	output in the high-impedance or power-off state (Note 2)	B ports	-0.5 to +6.5	V
77	Voltage Range applied to any	A ports	-0.5 to (V _{CCA} +0.5)	N/
$V_{\rm O}$	output in the high or low state (Note 2,3)	B ports	-0.5 to (V_{CCB} +0.5)	V
I_{IK}	Input Clamp Current	$V_I < 0$	-50	mA
I_{OK}	Output Clamp Current	$V_0 < 0$	-50	mA
I_{O}	Continuous Output Current		±50	mA
	Continuous Current through V _{CCA} , V ₀	_{CCB} , or GND	±100	mA
$\theta_{ m JA}$	Package Thermal Impedance		78	°C/W
T_{OP}	Operating Temperature Range		-40 to +85	${\mathcal C}$
T_{STG}	Storage Temperature Range		-65 to +150	$\mathcal C$

- Note 1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- Note 2: The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- Note 3: The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

Recommended Operating Conditions (Note 1, 2)

Symbol	Parame	eter	V _{CCA}	V_{CCB}	Min	Max	Unit
V_{CCA}	Cumple: V	altaga			1.2	3.6	V
V_{CCB}	Supply V	onage			1.65	5.5	V
W	High Level Input	Data Inputs	1.2V to 3.6V	1.65V to 5.5V	V _{CCI} ×0.65(Note3)	V _{CCI}	V
V_{IH}	Voltage	OE	1.2V to 3.6V	1.65V to 5.5V	V _{CCA} ×0.65	5.5	V
V	Low Level Input	Data Inputs	1.2V to 5.5V	1.65V to 5.5V	0 V_{CC}	$\times 0.35$	V
$V_{ m IL}$	Voltage	OE	1.2V to 3.6V	1.65V to 5.5V	V_{CC}	_A ×0.35	V
	I T	A-Port Inputs	1.2V to 3.6V	1.65V to 5.5V		40	
$\Delta t/\Delta V$	Rise or Fall Time	Input Transition		1.65V to 3.6V		40	ns/V
	Rise of Fair Time	B-Port Inputs	1.2V to 3.6V	4.5V to 5.5V		30	

- Note 1: The A and B sides of an unused data I/O pair must be held in the same state, i.e., both at V_{CCI} or both at GND.
- Note 2: V_{CCA} must be less than or equal to V_{CCB} and must not exceed 3.6 V.
- Note 3: V_{CCI} is the supply voltage associated with the input port.



Electrical Characteristics (Note 1, 2)

Over recommended operating free-air temperature range (unless otherwise noted)

Param	noton	Test Conditions	V_{CCA}	V	$T_A = 2$	25℃	-40℃ to	85℃	Unit
1 al all	ietei	Test Conditions		V_{CCB}	Тур	Max	Min	Max	Omt
V_{OI}	**	I _{OH} =-20μA	1.2V		1.1				V
V OF	НA	10H=-20μΑ	1.4V to 3.6V				V_{CCA} -0.4		•
V_{OI}		I _{OL} =20μA	1.2V		0.9				V
		•	1.4V to 3.6V					0.4	
V_{OI}	łВ	I_{OH} =-20 μ A		1.65V to 5.5V			V_{CCB} -0.4		V
V _{OI}	_B	$I_{OL}=20\mu A$		1.65V to 5.5V				0.4	V
$I_{\rm I}$	OE		1.2V to 3.6V	1.65V to 5.5V		±1		<u>+2</u>	μA
I _{off} A	Port		0V	0V to 5.5V		±1		<u>+2</u>	μA
¹ off B	Port		0V to 3.6V	0V		±1		<u>+2</u>	μА
I _{OZ} A or	r B Port	OE=GND	1.2V to 3.6V	1.65V to 5.5V		±1		<u>±2</u>	μA
			1.2V	1.65V to 5.5V	0.06				
т		$V_I = V_{CCI}$ or GND	1.4V to 3.6V	1.65V to 5.5V				5	
I_{CC}	A	$I_{O}=0$	3.6V	0V				2	μA
			0V	5.5V				-2	
			1.2V	1.65V to 5.5V	3.4				
_		V _I =V _{CCI} or GND	1.4V to 3.6V	1.65V to 5.5V				5	
I_{CC}	В	$I_0=0$	3.6V	0V				-2	μA
			0V	5.5V				2	
T .	T	V _I =V _{CCI} or GND	1.2V	1.65V to 5.5V	3.5				4
I _{CCA} +	1 _{CCB}	$I_{O}=0$	1.4V to 3.6V	1.65V to 5.5V				10	μA
ī		V _I =V _{CCI} or GND	1.2V	1.65V to 5.5V	0.05				۸
I _{CCZ}	ZA	I _O =0, OE=GND	1.4V to 3.6V	1.65V to 5.5V				5	μA
I _{CC2}		V _I =V _{CCI} or GND	1.2V	1.65V to 5.5V	3.3				μA
1CC2	ZB	I _O =0, OE=GND	1.4V to 3.6V	1.65V to 5.5V				5	μΑ
C _i	OE		1.2V to 3.6V	1.65V to 5.5V	5			5.5	pF
Cio	Port		1.2V to 3.6V	1.65V to 5.5V	5 8		_	6.5 10	pF
N 1 X	Port	1 1,	11		0			10	

Note 1: V_{CCI} is the supply voltage associated with the input port. Note 2: V_{CCO} is the supply voltage associated with the output port.



Switching Characteristics

 $T_A=+25$ °C, $V_{CCA}=1.2V$

Parameter	From	To	$V_{CCB}=1.8V$	$V_{\text{CCB}}=2.5V$	$V_{CCB}=3.3V$	$V_{CCB}=5V$	Unit
rarameter	(Input) (Output)		Typ	Typ	Typ	Тур	Omt
4	f.,		7	6	5.3	5.5	
t_{pd}	В	A	7.5	6.5	6	6	ns
4	OE	A	1	1	1	1	
t _{en}	OE	В	1	1	1	1	μs
4	OE	A	18	16	14	14	
$t_{ m dis}$	OE	В	19	17	15	15	ns
t_{rA}, t_{fA}		se and fall ne	5	5	5	5	ns
$t_{\rm rB}, t_{\rm fB}$	-	B port rise and fall time		1.5	1.2	1	ns
$t_{SK(O)}$			0.5	0.5	0.5	1.5	ns
Max data rate			20	20	20	20	Mbps

Switching Characteristics

Over recommended operating free-air temperature range, V_{CCA} =1.5V±0.1V (unless otherwise noted)

Parameter	From	To		=1.8V 15V		=2.5V .2V		=3.3V .3V		₃=5V .5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	
	A	В	2	15	1.2	11	1.1	10	1	10	nc
t_{pd}	В	A	1	15	0.9	12	0.5	12	0.3	13	ns
4	OE	A		1		1		1		1	116
t _{en}	OE	В		1		1		1		1	μs
+	OE	A	6	30	5.5	28	5.5	25	5.5	23	ne
$t_{ m dis}$	OL	В	5.5	30	5	25	5	20	5	20	ns
t_{rA}, t_{fA}	• .	se and fall ne	1.5	5.0	1.5	5.0	1.5	5.0	1.5	5.0	ns
t_{rB}, t_{fB}	•	se and fall ne	0.9	4.5	0.6	3.5	0.5	3	0.4	2.5	ns
$t_{SK(O)}$	Channel-t	to-channel		0.5		0.5		0.5		0.5	ns
Max data rate			40		40		40		40		Mbps



Switching Characteristics

Over recommended operating free-air temperature range, $V_{\text{CCA}} = 1.8 \text{V} \pm 0.15 \text{V}$ (unless otherwise noted)

Parameter	From			V _{CCB} =1.8V ±0.15V		V _{CCB} =2.5V ±0.2V		V _{CCB} =3.3V ±0.3V		_B =5V .5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	Min	Max	Min	Max	
+	A	В	1.6	10	1.4	9	1.3	7	1.2	6.5	ne
t_{pd}	В	A	1.5	12	1.3	8.5	1	8	0.9	8	ns
4	OE	A		1		1		1		1	
t _{en}	OE	В		1		1		1		1	μs
4	OE	A	6	34	5.5	23	5	20	5	17.6	
$t_{ m dis}$	OL	В	5.5	33	4.5	22	4.2	16.8	4.4	16.3	ns
t_{rA}, t_{fA}		se and fall ne	1	4.2	1.1	4.0	1.1	4.0	1.1	4.0	ns
$t_{rB,}t_{fB}$	· .	se and fall ne	0.9	4	0.6	3.2	0.5	2.8	0.4	2.8	ns
$t_{SK(O)}$	Channel-t	to-channel		0.5		0.5		0.5		0.5	ns
Max data rate			60		60		60		60		Mbps

Switching Characteristics

Over recommended operating free-air temperature range, V_{CCA} =2.5V±0.2V (unless otherwise noted)

Parameter	From (Input)	To (Output)		=2.5V .2V		=3.3V .3V	V _{CCB} =5V ±0.5V		Unit
	(Input)	(Output)	Min	Max	Min	Max	Min	Max	
+	A	В	1.1	6.5	1	5.2	0.9	5	ne
t_{pd}	В	A	1.2	6.6	1.1	5.1	0.9	4.4	ns
4	OE	A		1		1		1	
t _{en}	OE	В		1		1		1	μs
4	OE	A A		23	4.6	15.2	4.6	13	ne
$t_{ m dis}$	OE	В	4.4	22	3.8	16	3.9	13.3	ns
t_{rA}, t_{fA}	A port rise a	nd fall time	0.8	3	0.8	3	0.8	3	ns
$t_{\rm rB}, t_{\rm fB}$	B port rise a	nd fall time	0.7	2.7	0.5	2.8	0.4	2.7	ns
t _{SK(O)}	Channel-to-channel			0.5		0.5		0.5	ns
Max data rate			100		100		100		Mbps



Switching Characteristics

Over recommended operating free-air temperature range, V_{CCA} =3.3V±0.3V (unless otherwise noted)

Parameter	From	To (Output)		V _{CCB} =3.3V ±0.3V		_B =5V 0.5V	Unit
	(Input)	(Output)	Min	Max	Min	Max	
+	A	В	0.9	5	0.8	4	nc
t_{pd}	В	A	1	5.1	0.9	4	ns
4	OE	A		1		1	
t_{en}	OE	В		1		1	μs
4	OE	A	5	15	4	13	
$t_{ m dis}$	OE	В	4	16	3.4	13.8	ns
t_{rA}, t_{fA}	A port rise a	nd fall time	0.7	2.5	0.7	2.5	ns
$t_{\rm rB}, t_{\rm fB}$	B port rise a	nd fall time	0.5	2.1	0.4	2.8	ns
$t_{SK(O)}$	Channel-t	o-channel		0.5		0.5	ns
Max data rate			100		100		Mbps

Operating Characteristics

 $T_A=+25 \degree C$

						V _{CCB}						
Pamameter		Test	5V	1.8V	1.8V	1.8V	2.5V	5V	3.3V to 5V	Unit		
r	amameter	Conditions		$ m V_{CCA}$								
			1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V			
			Тур	Тур	Тур	Тур	Тур	Тур	Тур			
	A-port input B-port output		9	10	10	10	10	10	10			
CpdA	C _{pdA} B-port input A-port output	$C_L=0,$ f=10MHz,	12	11	11	11	11	11	11			
C	A-port input B-port output	$t_r=t_f=1$ ns, OE= V_{CCA}	35	28	28	29	3.0	30	30	pF		
C_{pdB}	B-port input A-port output		27	19	19	19	20	21	23			
C	A-port input B-port output		0.01	0.01	0.01	0.01	0.01	0.01	0.01			
C_{pdA}	B-port input A-port output	C _L =0, f=10MHz,	0.01	0.01	0.01	0.01	0.01	0.01	0.01	»E		
C	A-port input B-port output	$t_r=t_f=1 \text{ns},$ OE= GND	0.01	0.01	0.01	0.01	0.01	0.01	0.03	pF		
C_{pdB}	B-port input A-port output		0.01	0.01	0.01	0.01	0.01	0.01	0.05			



Applications Information

UM3308 ESD protected level translator provides level shifting necessary to allow data transfer in a multi-voltage system. Externally applied voltages, V_{CCA} and V_{CCB} set the logic levels on either side of device. A low voltage signal present on V_{CCA} side of the device appears as a high voltage logic signal on the V_{CCB} side of the device, and vice-versa.

Block Diagram

The UM3308 (block diagram see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a dc state, the output drivers of the UM3308 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing to the opposite direction.

The output one shot detects rising or falling edges on the A or B ports. During a rising edge, the one shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition.

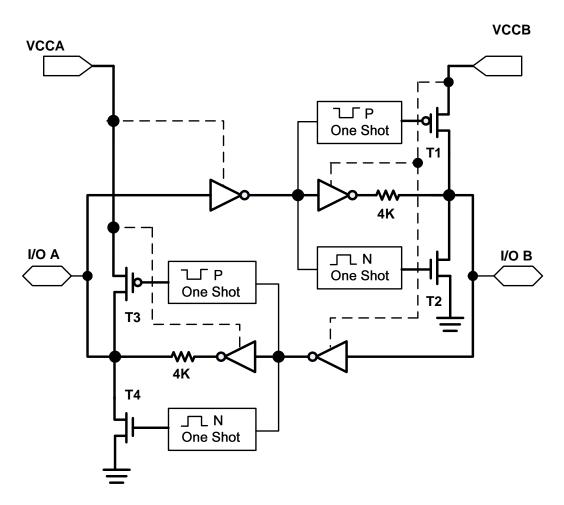
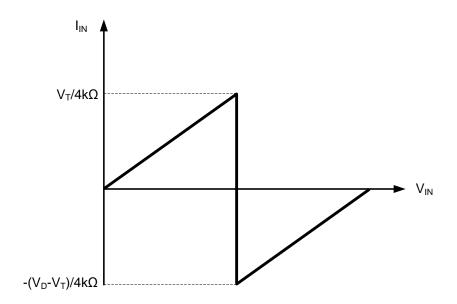


Figure 1 Block Diagram of UM3308 I/O Cell



Input Driver Requirements

Typical I_{IN} vs V_{IN} characteristics of the UM3308 are shown in Figure 2. For proper operation, the device driving the data I/Os of the UM3308 must have drive strength of at least ± 2 mA.



A: V_T is the input threshold voltage of the UM3308 (typical V_{CCI}/2)

B: V_D is the supply voltage of the external driver.

Figure 2 Typical I_{IN} vs V_{IN} Curve

Power Up

During operation, ensure that $V_{CCA} \le V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \ge V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The UM3308 has circuitry that disables all output ports when either V_{CC} is switched off ($V_{CCA/B} = 0$ V).

Enable and Disable

The UM3308 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (tdis) indicates the delay between when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (ten) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Pullup or Pulldown Resistors on I/O Lines

The UM3308 is designed to drive capacitive loads of up to 50pF. The output drivers of the UM3308 have low dc drive strength. If pullup or pulldown resistors are connected externally to the data I/Os, their values must be kept higher than 50 k Ω to ensure that they do not contend with the output drivers of theUM3308.

For the same reason, the UM3308 should not be used in applications such as I²C or 1-Wire where an open-drain driver is connected on the bidirectional data I/O.



Typical Operating Circuit

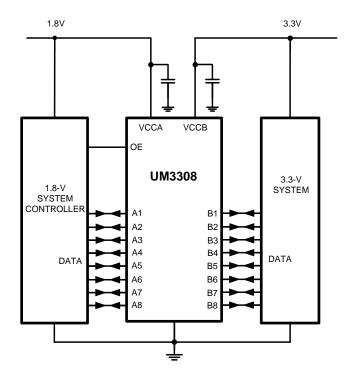
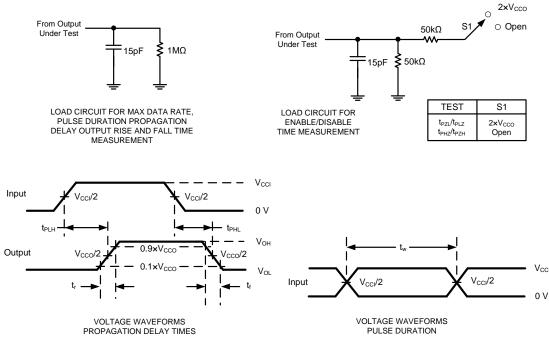


Figure 3 Typical operating circuit

Test Circuits



- A. C_L includes probe and jig capacitance.

 B. All input pulses are supplied by generators having the following characteristics: PRR≤10MHz, Z₀=50Ω,dv/dt≥1V/ns.

 C. The outputs are measured one at a time, with one transition per measurement.

 D. t_{PLH} and t_{PHL} are the same as t_{pd}.

 E. V_{CCI} is the V_{CC} associated with the input port.

- F. V_{CCO} is the V_{CC} associated with the output port. G. All parameters and waveforms are not applicable to all devices.

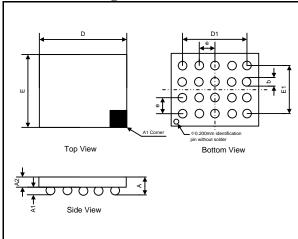
Figure 4 Load Circuits and Voltage Waveforms



Package Information

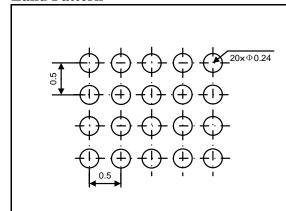
UM3308: CSP20 2.7×2.4

Outline Drawing



DIMENSIONS				
Symbol	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A		0.63		0.025
A1	0.21	0.24	0.008	0.010
A2	0.37	0.39	0.015	0.016
D	2.60	2.80	0.104	0.112
Е	2.28	2.48	0.091	0.099
D1	2.00BSC		0.08BSC	
E1	1.50BSC		0.06BSC	
e	0.50BSC		0.02BSC	
b	0.27	0.32	0.011	0.013

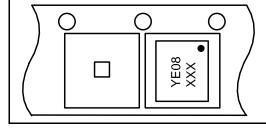
Land Pattern



NOTES:

- 1. Bump is Lead Free Sn/Ag/Cu.
- 2. Unit: mm.
- 3. Non-solder mask defined copper landing pad.
- 4. Laser Mark on silicon die back; back-lapped.

Tape and Reel Orientation





IMPORTANT NOTICE

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